








	<h2>SI1499DH-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI1499DH-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET P-CH 8V 1.6A SC-70-6</p> <p>Datenblätter:  SI1499DH-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 21578 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1499DH-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 8V 1.6A SC-70-6
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	21578 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-70-6 (SOT-363)
Verlustleistung (max)	2.5W (Ta), 2.78W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.6A (Tc)
Rds On (Max) @ Id, Vgs	78 mOhm @ 2A, 4.5V
VGS (th) (Max) @ Id	800mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	650pF @ 4V
Antriebsspannung (Max Rds On, Min Rds On)	1.2V, 4.5V
Vgs (Max)	±5V
Verpackung	Tape & Reel (TR)

















































SI1499DH-T1-GE3 ist neu im Original, Suche SI1499DH-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1499DH-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1499DH-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1499DH-T1-E3 Vishay / Siliconix MOSFET P-CH 8V 1.6A SC70-6</p>	 <p>SI1500 50G BTL 3M SCOTCH-WELD SURFACE INSENSITIVE</p>	 <p>SI1500 500G BTL 3M SCOTCH-WELD SURFACE INSENSITIVE</p>	 <p>SI1501DL VISHAY SI1501DL VISHAY</p>
 <p>SI1499DH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 1.6A SC-70-6</p>	 <p>SI1501DL-T1 VISHAY SI1501DL-T1 VISHAY</p>	 <p>SI1489EDH-T1-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 8V 2A SOT-363</p>	 <p>SI1489EDH-T1-GE3 Vishay / Siliconix MOSFET P-CH 8V 2A SOT-363</p>

heiße Teile

Mehr

 SI1443EDH-T1-GE3	 SI1443EDH-T1-GE3	 SI1467DH-T1-GE3	 SI1467DH-T1-GE3	 SI1469DH-T1-GE3
 SI1469DH-T1-GE3	 SI1470DH-M6TR	 SI1470DH-T1-GE3	 SI1470DH-T1-GE3	 SI1471DH-T1
 SI1471DH-T1-E3	 SI1471DH-T1-E3	 SI1471DH-T1-GE3	 SI1471DH-T1-GE3	 SI1472DH-T1-E3
 SI1472DH-T1-E3	 SI1473DH-T1-E3	 SI1473DH-T1-E3	 SI1473DH-T1-GE3	 SI1473DH-T1-GE3
 SI1488DH-T1-GE3	 SI1488DH-T1-GE3	 SI1489EDH-T1-GE3	 SI1489EDH-T1-GE3	 SI1499DH-T1-GE3
 SI1501DL	 SI1501DL-T1	 SI1501DL-T1-E3	 SI1501DL-T1-GE3	 SI1539CDL-T1-GE3
 SI1539CDL-T1-GE3	 SI1539DL	 SI1539DL-T1-E3	 SI1539DL-T1-E3	 SI1539DL-T1-GE3
 SI1539DL-T1-GE3	 SI1551DL	 SI1551DL-S6-E3	 SI1551DL-T1	 SI1551DL-T1-E3
 SI1551DL-T1-E3	 SI1551DL-T1-GE3	 SI1551DL-T1-GE3	 SI1552AI-JE-DCC-32.768D	 SI1553CDL-T1-GE3
 SI1553CDL-T1-GE3	 SI1553DL	 SI1553DL-F1	 SI1553DL-T1	 SI1553DL-T1

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